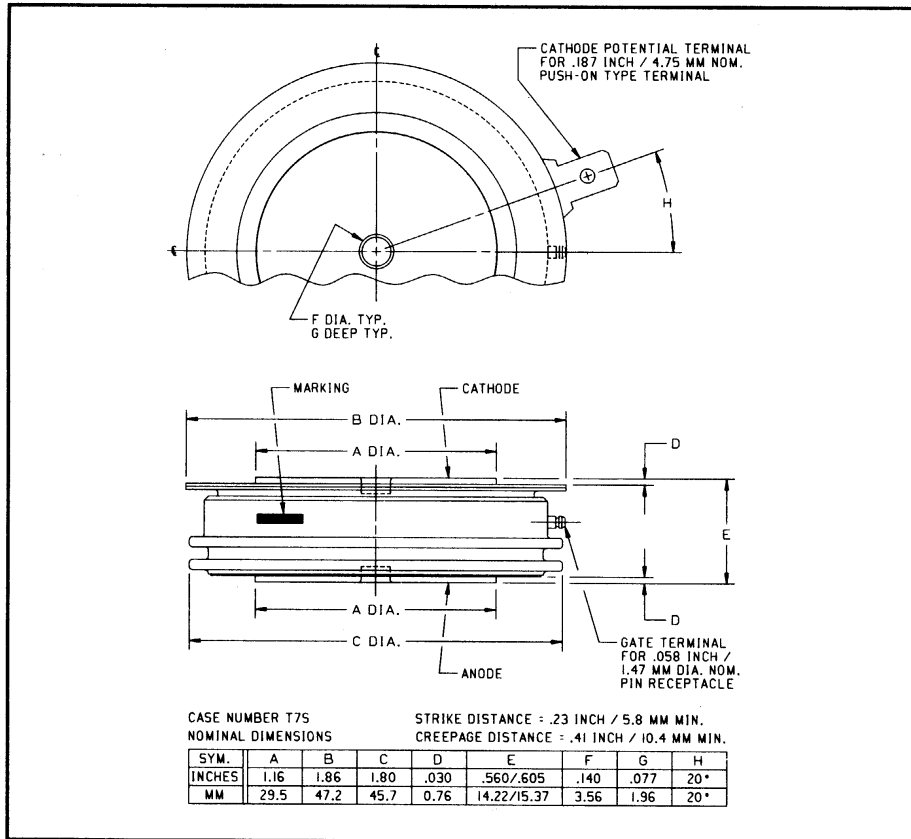


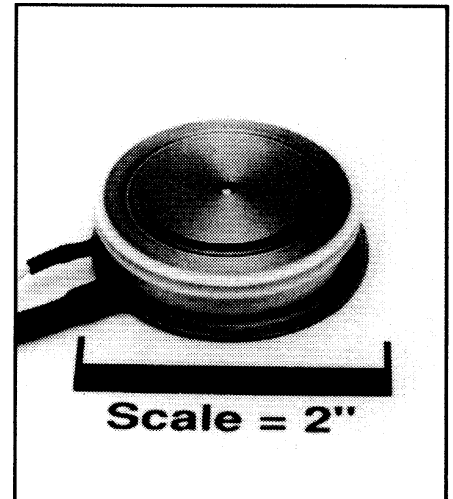
Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272
Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

Phase Control SCR

650 Amperes Average
1800-2400 Volts



T7S0 650A (1800-2400V) (Outline Drawing)



T7S0 650A (2400V) Phase Control SCR
650 Amperes Average, 1800-2400 Volts

Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak, hermetic Pow-R-Disc devices employing the field proven amplifying gate.

Features:

- Low On-State Voltage
- High di/dt Capability
- High dv/dt Capability
- Hermetic Packaging
- Excellent Surge and I²t Ratings

Applications:

- Power Supplies
- Motor Control

Ordering Information:

Select the complete 12 digit part number you desire from the table below.

Type	Voltage	Current	Turn-off	Gate Current	Lead Code
	V _{DRM} /V _{RRM} (Volts)	I _{T(av)} (A)	t _q (μsec)	I _{GT} (mA)	
T7S0	18 20 24	65	0	4	DN
	1800V 2000V 2400V	650A	150μsec (Typical)	150mA	8"

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T7S0 650A (2400V)
Phase Control SCR
 650 Amperes Average, 1800-2400 Volts

Absolute Maximum Ratings

Characteristics	Symbol	T7S0 650A (2400V)	Units
Non-repetitive Transient Peak Reverse Voltage	V_{RSM}	$V_{RRM} + 100V$	Volts
RMS On-state Current, $T_C = 70^\circ C$	$I_{T(rms)}$	1020	Amperes
Average Current 180° Sine Wave, $T_C = 70^\circ C$	$I_{T(av)}$	650	Amperes
RMS On-state Current, $T_C = 55^\circ C$	$I_{T(rms)}$	1270	Amperes
Average Current 180° Sine Wave, $T_C = 55^\circ C$	$I_{T(av)}$	810	Amperes
Peak One Cycle Surge On-state Current (Non-repetitive) 60Hz	I_{tsm}	9000	Amperes
Peak One Cycle Surge On-state Current (Non-repetitive) 50Hz	I_{tsm}	8200	Amperes
Critical Rate-of-rise of On-state Current (Non-repetitive)	di/dt	600	A/ μ sec
Critical Rate-of-rise of On-state Current (Repetitive)	di/dt	150	A/ μ sec
I^2t (for Fusing) for One Cycle, 60Hz	I^2t	338,000	A ² sec
Peak Gate Power Dissipation	P_{GM}	16	Watts
Average Gate Power Dissipation	$P_{G(av)}$	3	Watts
Operating Temperature	T_j	-40 to +125°C	°C
Storage Temperature	T_{stg}	-40 to +150°C	°C
Approximate Weight		4	oz.
		113	g
Mounting Force		2000 to 2400	lb.
		900 to 1090	kg.

Electrical Characteristics, $T_j = 25^\circ\text{C}$ Unless Otherwise Specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Repetitive Peak Reverse Leakage Current	I_{RRM}	$T_j = 125^\circ\text{C}, V_R = V_{RRM}$			30	mA
Repetitive Peak Forward Leakage Current	I_{DRM}	$T_j = 125^\circ\text{C}, V_D = V_{DRM}$			30	mA
Peak On-state Voltage	V_{TM}	$I_{TM} = 625\text{A Peak}$ Duty Cycle < 0.1%			1.50	Volts
Threshold Voltage, Low-level	$V_{(TO)1}$	$T_j = 125^\circ\text{C}, I = 15\%, I_{T(av)} \text{ to } \pi I_{T(av)}$			0.99967	Volts
Slope Resistance, Low-level	r_{T1}				0.70105	m Ω
Threshold Voltage, High-level	$V_{(TO)2}$	$T_j = 125^\circ\text{C}, I = \pi I_{T(av)} \text{ to } I_{TSM}$			1.5734	Volts
Slope Resistance, High-level	r_{T2}				0.3897	m Ω
V_{TM} Coefficients, Low-level		$T_j = 125^\circ\text{C}, I = 15\% I_{T(av)} \text{ to } \pi I_{T(av)}$				
					$A_1 = 0.76237$	
					$B_1 = 0.02889$	
					$C_1 = 4.486\text{E-}04$	
					$D_1 = 0.00954$	
V_{TM} Coefficients, High-level		$T_j = 125^\circ\text{C}, I = \pi I_{T(av)} \text{ to } I_{TSM}$				
					$A_2 = -2.3231$	
					$B_2 = 0.64507$	
					$C_2 = 3.519\text{E-}04$	
					$D_2 = -0.0179$	
Typical Turn-on Time	t_{on}	$I_T = 100\text{A}, V_D = 100\text{V}$		7		μsec
Typical Turn-off Time	t_q	$T_j = 125^\circ\text{C}, I_T = 250\text{A},$ $di_T/dt = 25\text{A}/\mu\text{sec Reapplied}$ $dv/dt = 20\text{V}/\mu\text{sec Linear to}$ $80\% V_{DRM}$		150		μsec
Minimum Critical dv/dt - Exponential to V_{DRM}	dv/dt	$T_j = 125^\circ\text{C}$	300			V/ μsec
Gate Trigger Current	I_{GT}	$T_j = 25^\circ\text{C}, V_D = 12\text{V}$			150	mA
Gate Trigger Voltage	V_{GT}	$T_j = 25^\circ\text{C}, V_D = 12\text{V}$			3.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_j = 125^\circ\text{C}, V_D = V_{DRM}$			0.15	Volts
Peak Forward Gate Current	I_{GTM}				4	A
Peak Reverse Gate Voltage	V_{GRM}				5	Volts

Thermal Characteristics

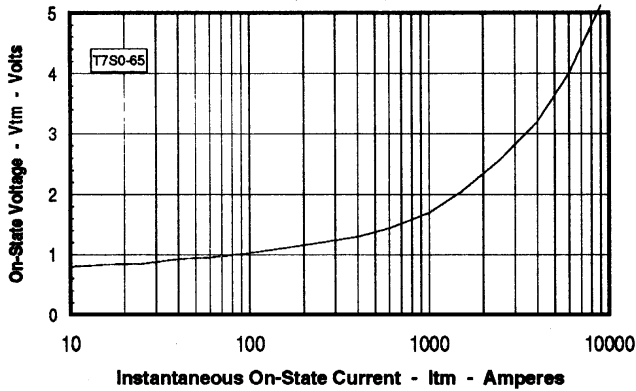
Maximum Thermal Resistance, Double Sided Cooling

Junction-to-Case	$R_{\theta(j-c)}$	0.035	$^\circ\text{C/W}$
Case-to-Sink	$R_{\theta(c-s)}$	0.02	$^\circ\text{C/W}$

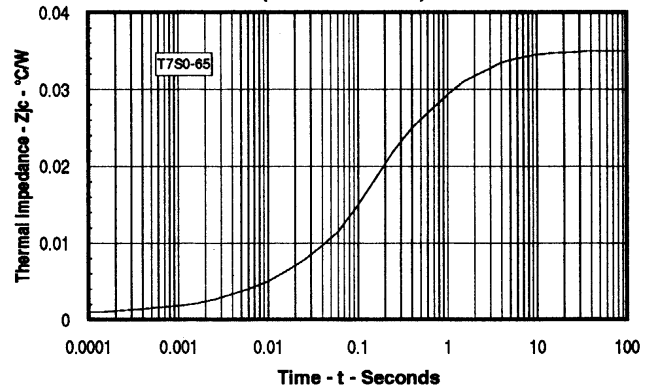
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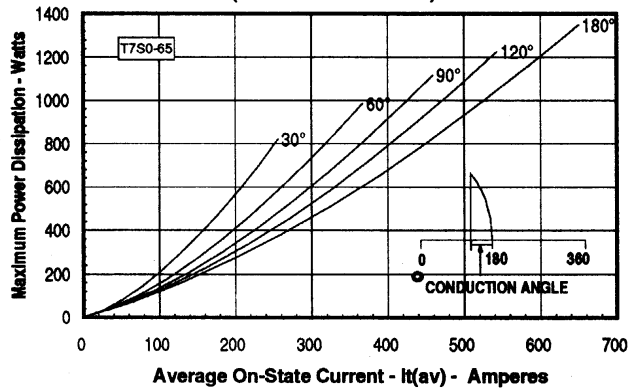
Maximum On-State Forward Voltage Drop
 ($T_J = 125^\circ\text{C}$)



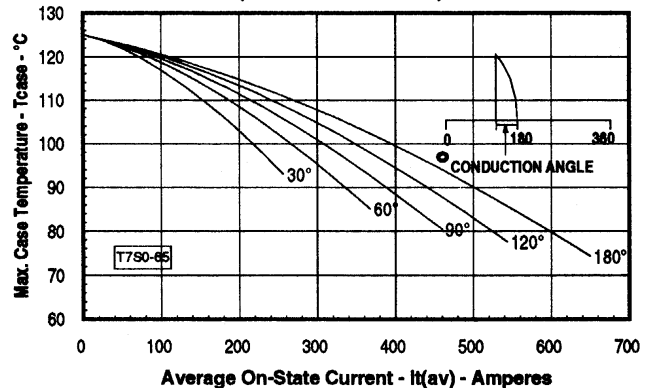
Maximum Transient Thermal Impedance
 (Junction to Case)



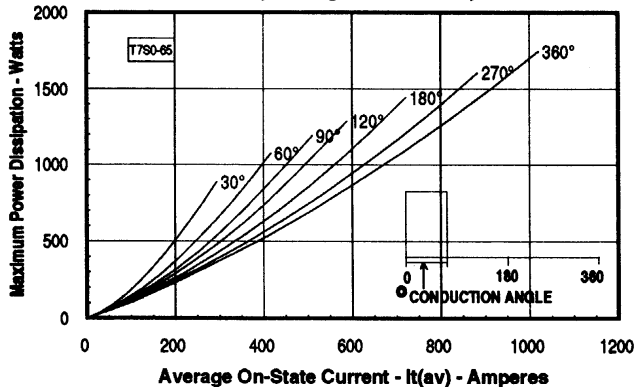
Maximum On-State Power Dissipation
 (Sinusoidal Waveform)



Maximum Allowable Case Temperature
 (Sinusoidal Waveform)



Maximum On-State Power Dissipation
 (Rectangular Waveform)



Maximum Allowable Case Temperature
 (Rectangular Waveform)

